

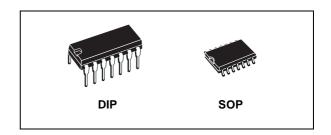


## **QUAD 2 INPUT OR GATE**

- MEDIUM SPEED OPERATION:  $t_{PD} = 60$ ns (TYP.) at  $V_{DD} = 10$ V
- QUIESCENT CURRENT SPECIFIED UP TO
- 5V, 10V AND 15V PARAMETRIC RATINGS
- INPUT LEAKAGE CURRENT I<sub>I</sub> = 100nA (MAX) AT V<sub>DD</sub> = 18V T<sub>A</sub> = 25°C
- 100% TESTED FOR QUIESCENT CURRENT
- MEETS ALL REQUIREMENTS OF JEDEC JESD13B " STANDARD SPECIFICATIONS FOR DESCRIPTION OF B SERIES CMOS DEVICES"

#### **DESCRIPTION**

The HCF4071B is a monolithic integrated circuit fabricated in Metal Oxide Semiconductor technology available in DIP and SOP packages. The HCF4071B QUAD 2 INPUT OR GATE provides the system designer with direct

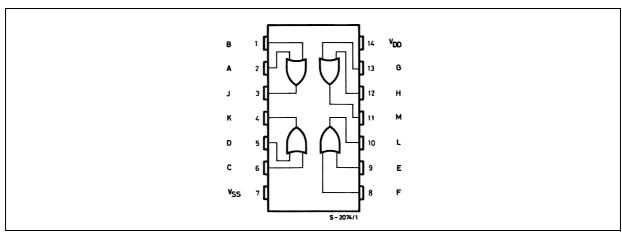


#### **ORDER CODES**

PACKAGE	TUBE	T&R
DIP	HCF4071BEY	
SOP	HCF4071BM1	HCF4071M013TR

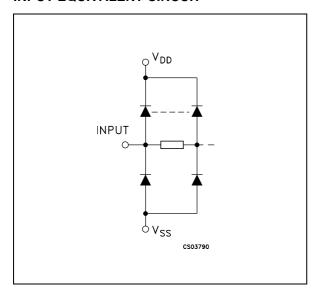
implementation of the positive logic OR function and supplement the existing family of CMOS gates.

### **PIN CONNECTION**



September 2001 1/7

## **INPUT EQUIVALENT CIRCUIT**



## **PIN DESCRIPTION**

PIN No	SYMBOL	NAME AND FUNCTION
2, 6, 9, 12	A, C, E, H	Data Inputs
1, 5, 8, 13	B, D, F, G	Data Inputs
3, 4, 10, 11	J, K, L, M	Data Outputs
7	$V_{SS}$	Negative Supply Voltage
14	$V_{DD}$	Positive Supply Voltage

## **TRUTH TABLE**

INP	INPUTS					
A, C, E, H	B, D, F, G	J, K, L, M				
L	L	L				
L	Н	Н				
Н	L	Н				
Н	Н	Н				

## **ABSOLUTE MAXIMUM RATINGS**

Symbol	Parameter	Value	Unit
$V_{DD}$	Supply Voltage	-0.5 to +22	V
V <sub>I</sub>	DC Input Voltage	-0.5 to V <sub>DD</sub> + 0.5	V
I <sub>I</sub>	DC Input Current	± 10	mA
P <sub>D</sub>	Power Dissipation per Package	200	mW
	Power Dissipation per Output Transistor	100	mW
T <sub>op</sub>	Operating Temperature	-55 to +125	°C
T <sub>stg</sub>	Storage Temperature	-65 to +150	°C

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these conditions is not implied.

All voltage values are referred to V<sub>SS</sub> pin voltage.

#### 7 iii renage value ale relenea te 155 piii renage.

**RECOMMENDED OPERATING CONDITIONS** 

Symbol	Parameter	Value	Unit
V <sub>DD</sub>	Supply Voltage	3 to 20	V
V <sub>I</sub>	Input Voltage	0 to V <sub>DD</sub>	V
T <sub>op</sub>	Operating Temperature	-55 to 125	°C

2/7

## **DC SPECIFICATIONS**

			Test Con	dition					Value				
Symbol	Parameter	VI	٧o	l <sub>o</sub>	V <sub>DD</sub>	Т	A = 25°	С	-40 to	85°C	-55 to	125°C	Unit
		(V)	(V)	(μ <b>A</b> )	(V)	Min.	Тур.	Max.	Min.	Max.	Min.	Max.	
ΙL	Quiescent Current	0/5			5		0.01	0.25		7.5		7.5	
		0/10			10		0.01	0.5		15		15	μΑ
		0/15			15		0.01	1		30		30	μΛ
		0/20			20		0.02	5		150		150	
$V_{OH}$	High Level Output	0/5		<1	5	4.95			4.95		4.95		
	Voltage	0/10		<1	10	9.95			9.95		9.95		V
		0/15		<1	15	14.95			14.95		14.95		
$V_{OL}$	Low Level Output	5/0		<1	5		0.05			0.05		0.05	
	Voltage	10/0		<1	10		0.05			0.05		0.05	V
		15/0		<1	15		0.05			0.05		0.05	
$V_{IH}$	High Level Input		0.5/4.5	<1	5	3.5			3.5		3.5		
	Voltage		1/9	<1	10	7			7		7		V
			1.5/13.5	<1	15	11			11		11		
$V_{IL}$	Low Level Input		4.5/0.5	<1	5			1.5		1.5		1.5	
	Voltage		9/1	<1	10			3		3		3	V
			13.5/1.5	<1	15			4		4		4	
I <sub>OH</sub>	Output Drive	0/5	2.5	<1	5	-1.36	-3.2		-1.15		-1.1		
	Current	0/5	4.6	<1	5	-0.44	-1		-0.36		-0.36		mA
		0/10	9.5	<1	10	-1.1	-2.6		-0.9		-0.9		ША
		0/15	13.5	<1	15	-3.0	-6.8		-2.4		-2.4		
$I_{OL}$	Output Sink	0/5	0.4	<1	5	0.44	1		0.36		0.36		
	Current	0/10	0.5	<1	10	1.1	2.6		0.9		0.9		mΑ
		0/15	1.5	<1	15	3.0	6.8		2.4		2.4		
I <sub>I</sub>	Input Leakage Current	0/18	Any In	put	18		±10 <sup>-5</sup>	±0.1		±1		±1	μΑ
C <sub>I</sub>	Input Capacitance		Any In	put			5	7.5					pF

The Noise Margin for both "1" and "0" level is: 1V min. with  $V_{DD}$ =5V, 2V min. with  $V_{DD}$ =10V, 2.5V min. with  $V_{DD}$ =15V

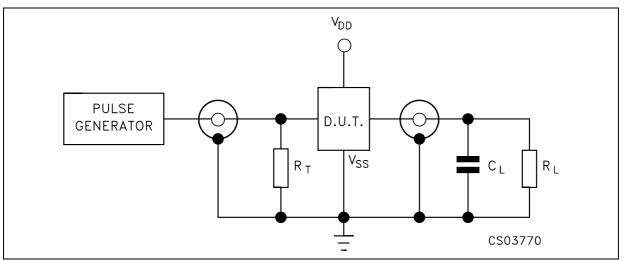
# $\textbf{DYNAMIC ELECTRICAL CHARACTERISTICS} \; (\textbf{T}_{amb} = 25^{\circ} \textbf{C}, \;\; \textbf{C}_{L} = 50 \text{pF}, \; \textbf{R}_{L} = 200 \text{K}\Omega, \;\; \textbf{t}_{r} = \textbf{t}_{f} = 20 \; \text{ns})$

Cumbal	Parameter		,	Unit			
Symbol	Parameter	V <sub>DD</sub> (V)		Min.	Тур.	Max.	
t <sub>PHL</sub>	Propagation Delay Time	5			125	250	
		10			60	120	ns
		15			45	90	
t <sub>PLH</sub>	Propagation Delay Time	5			175	350	
		10			50	140	ns
		15			50	140	
t <sub>TLH</sub> t <sub>THL</sub>	Output Transition Time	5			100	200	
		10			50	100	ns
		15			40	80	

<sup>(\*)</sup> Typical temperature coefficient for all  $\rm V_{DD}$  value is 0.3 %/°C.

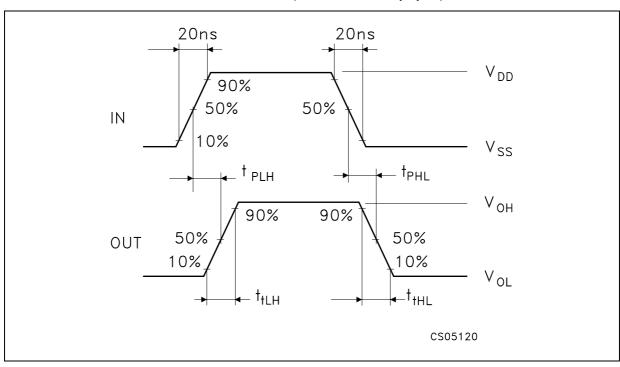
47/

## **TEST CIRCUIT**



 $C_L$  = 50pF or equivalent (includes jig and probe capacitance)  $R_L$  = 200 $K\Omega$   $R_T$  =  $Z_{OUT}$  of pulse generator (typically 50 $\Omega$ )

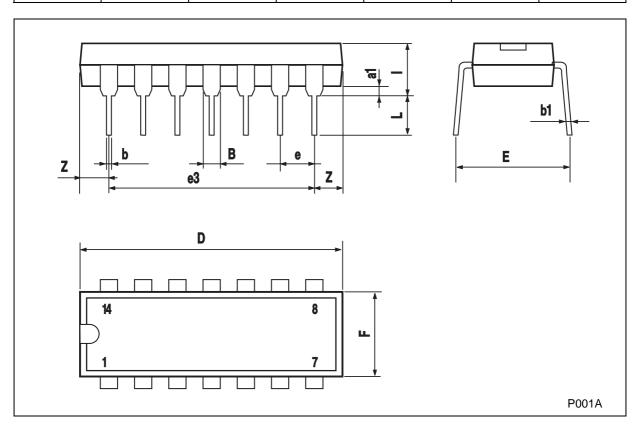
## WAVEFORM: PROPAGATION DELAY TIMES (f=1MHz; 50% duty cycle)



47/ 4/7

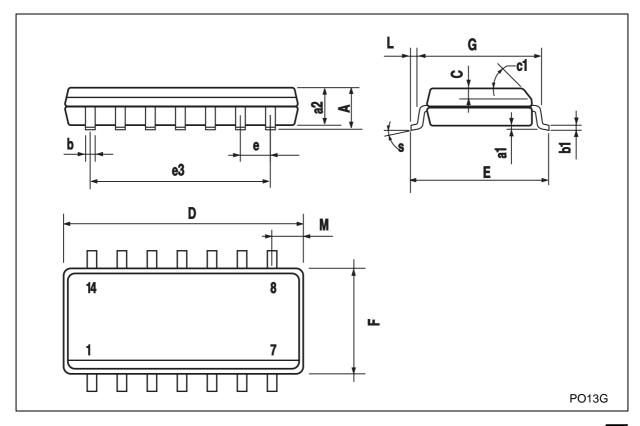
## **Plastic DIP-14 MECHANICAL DATA**

DIM.		mm.			inch			
DIIVI.	MIN.	TYP	MAX.	MIN.	TYP.	MAX.		
a1	0.51			0.020				
В	1.39		1.65	0.055		0.065		
b		0.5			0.020			
b1		0.25			0.010			
D			20			0.787		
E		8.5			0.335			
е		2.54			0.100			
e3		15.24			0.600			
F			7.1			0.280		
I			5.1			0.201		
L		3.3			0.130			
Z	1.27		2.54	0.050		0.100		



## **SO-14 MECHANICAL DATA**

DIM		mm.		inch				
DIM.	MIN.	TYP	MAX.	MIN.	TYP.	MAX.		
А			1.75			0.068		
a1	0.1		0.2	0.003		0.007		
a2			1.65			0.064		
b	0.35		0.46	0.013		0.018		
b1	0.19		0.25	0.007		0.010		
С		0.5			0.019			
c1			45°	(typ.)	•	•		
D	8.55		8.75	0.336		0.344		
E	5.8		6.2	0.228		0.244		
е		1.27			0.050			
e3		7.62			0.300			
F	3.8		4.0	0.149		0.157		
G	4.6		5.3	0.181		0.208		
L	0.5		1.27	0.019		0.050		
М			0.68			0.026		
S		-	8° (ı	max.)		4		



6/7

Information furnished is believed to be accurate and reliable. However, STMicroelectronics assumes no responsibility for the consequences of use of such information nor for any infringement of patents or other rights of third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of STMicroelectronics. Specifications mentioned in this publication are subject to change without notice. This publication supersedes and replaces all information previously supplied. STMicroelectronics products are not authorized for use as critical components in life support devices or systems without express written approval of STMicroelectronics.

© The ST logo is a registered trademark of STMicroelectronics

© 2001 STMicroelectronics - Printed in Italy - All Rights Reserved STMicroelectronics GROUP OF COMPANIES

Australia - Brazil - China - Finland - France - Germany - Hong Kong - India - Italy - Japan - Malaysia - Malta - Morocco Singapore - Spain - Sweden - Switzerland - United Kingdom © http://www.st.com



Copyright © Each Manufacturing Company.

All Datasheets cannot be modified without permission.

This datasheet has been download from:

www.AllDataSheet.com

100% Free DataSheet Search Site.

Free Download.

No Register.

Fast Search System.

www.AllDataSheet.com